



Description

The TD101X series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic LSOP4 package with the robust coplanar double mold structure. TD101X series provide the most stable isolation feature.

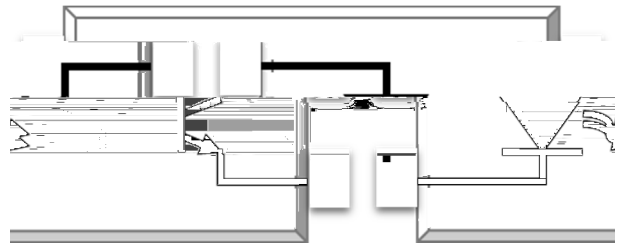
Features

- High isolation (1000) * +S
- Temperature stability available see order information
- DC input with transistor output
- Operating temperature range: (-40°C, to 110°C)
- Load current 10mA, RoHS compliance
- UL class 1
- Regulatory Approvals
 - 2L : 2L1(33)
 - D1 : 1450313.(6)D10771.(8)
 - 9, : G ; !< !=#1% G ; 77<7

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

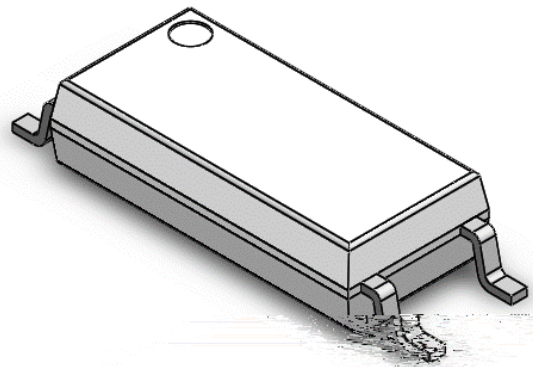
SCHEMATIC

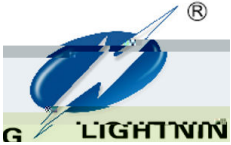


PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PAC A ! E O " T # I N E





LSOP4, DC Input, Photo Transistor Coupler

A ' SO# " TE MA (IM " M) ATIN ! S				
A * A + 1 T 1 *	S @ + ; OL) AL 2 1	2 4 AT	4 OT 1
A 4 2 T				
Borward , urrent	A _B	50	mA	
ea" Borward , urrent	A _B	1	A	1
* e&erse) oltage) *	5)	
Anput ower Dissipation	A	100	m\$	
O 2 T 2 T				
, ollector . 1 mitter) oltage) , 1 0	70)	
1 mitter . , ollector) oltage) 1 , 0	3)	
, ollector , urrent	A ,	(0	mA	
Output ower Dissipation	o	1 (0	m\$	
, O + + O 4				
Total ower Dissipation	tot	? (0	m\$	
Asolation) oltage) iso	(000) rms	?
Operating Temperature	Topr	. ((C 1 1 0	/ ,	
Storage Temperature	Tstg	. ((C 1 ? (/ ,	
Soldering Temperature	Tsol	? 50	/ ,	

Note 1. 100µs pulse, 100 ! "#e\$uenc%

Note 2. A & ' o# 1 () nute, R. . * +0 , -0.



LSOP4, DC Input, Photo Transistor Coupler

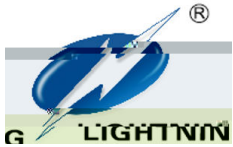
ELECTRICAL CHARACTERISTICS at Ta=25°C							
Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions	Notes
I_{F}	Forward Current	0	10	100	mA	$V_{CE} = 5V, I_{C} = 1mA$	
I_{C}	Collector Current	0	100	100	mA	$V_{CE} = 5V, I_{F} = 10mA$	
V_{CE}	Collector-Emitter Voltage	0	5	5	V	$I_{F} = 10mA, I_{C} = 1mA$	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	0.1	0.2	0.3	V	$I_{F} = 10mA, I_{C} = 1mA$	
β_{DC}	DC Current Gain	100	100	100		$I_{F} = 10mA, I_{C} = 1mA$	
β_{AC}	AC Current Gain	100	100	100		$I_{F} = 10mA, I_{C} = 1mA, f = 1kHz$	
f_T	Transition Frequency	5	5	5	MHz	$I_{F} = 10mA, I_{C} = 1mA$	
C_{in}	Input Capacitance	0	10	10	pF	$V_{CE} = 5V, I_{F} = 10mA$	
C_{out}	Output Capacitance	0	10	10	pF	$V_{CE} = 5V, I_{C} = 1mA$	
R_{SO}	Storage Time	0	10	10	ns	$I_{F} = 10mA, I_{C} = 1mA$	
t_{off}	Turn-off Time	0	10	10	ns	$I_{F} = 10mA, I_{C} = 1mA$	
t_{on}	Turn-on Time	0	10	10	ns	$I_{F} = 10mA, I_{C} = 1mA$	
t_{r}	Rise Time	0	10	10	ns	$I_{F} = 10mA, I_{C} = 1mA$	
t_{f}	Fall Time	0	10	10	ns	$I_{F} = 10mA, I_{C} = 1mA$	
$R_{th(j-c)}$	Thermal Resistance (junction to case)	10	10	10	°C/W		
$R_{th(c-a)}$	Thermal Resistance (case to ambient)	10	10	10	°C/W		
$R_{th(j-a)}$	Thermal Resistance (junction to ambient)	10	10	10	°C/W		
θ_{j-c}	Thermal Resistance (junction to case)	10	10	10	°C/W		
θ_{c-a}	Thermal Resistance (case to ambient)	10	10	10	°C/W		
θ_{j-a}	Thermal Resistance (junction to ambient)	10	10	10	°C/W		

Note 1. $I_{F} = 10mA$
 Note 2. $I_{C} = 1mA$



0\$. Collector3emitter -olta . e

0\$. Collector3emitt() - 2.33292 (F) 0.480 - 1



CHARACTERISTICS - ES

Fig. 5 Normalized Current Transfer Ratio vs. Forward Current

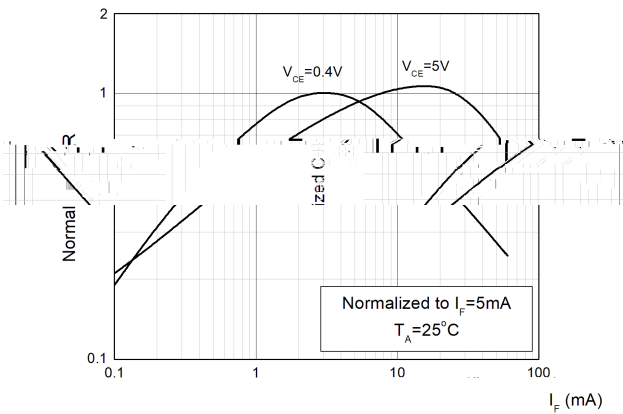


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature

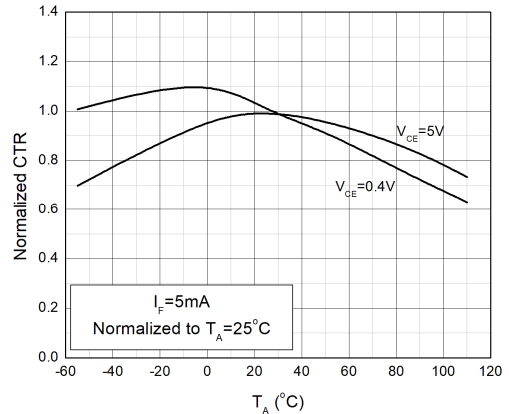


Fig. 9 Collector-Emitter Saturation Voltage vs. Ambient Temperature

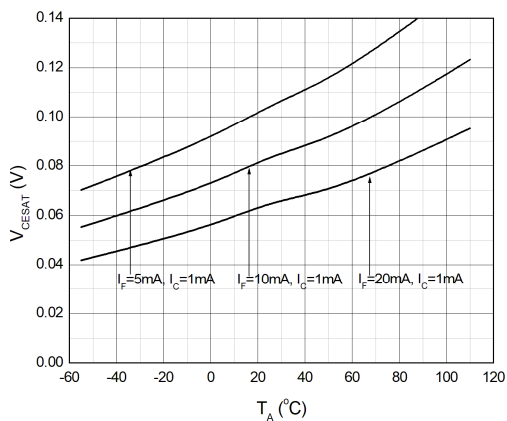


Fig. 10 Switching Time vs. Load Resistance

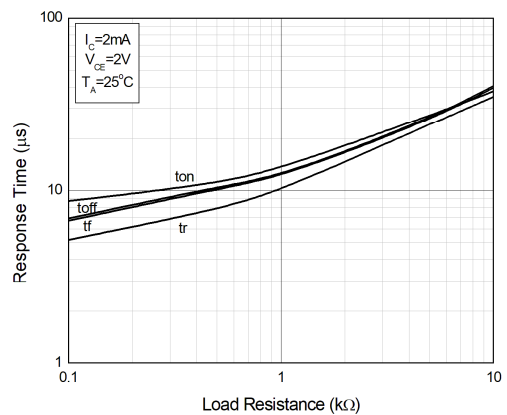
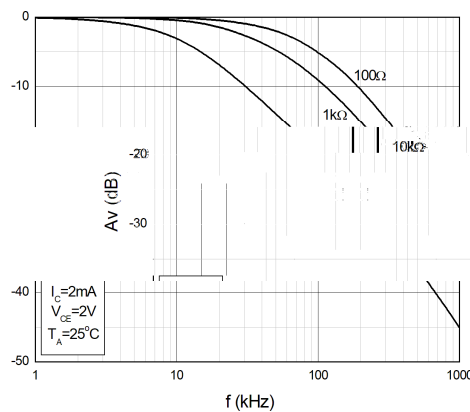
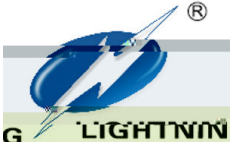


Fig. 11 Frequency Response





TEST CIRCUITS

Fig. 12 Test Circuit of Rise Time

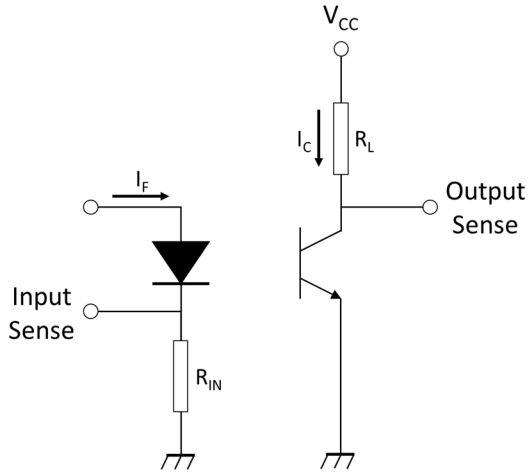


Fig. 13 Characteristic of Rise Time

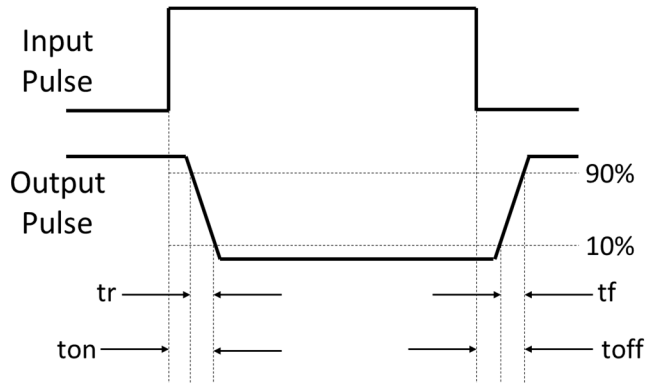
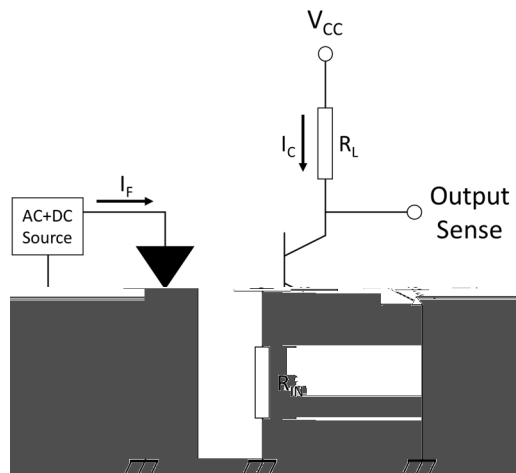
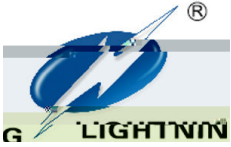
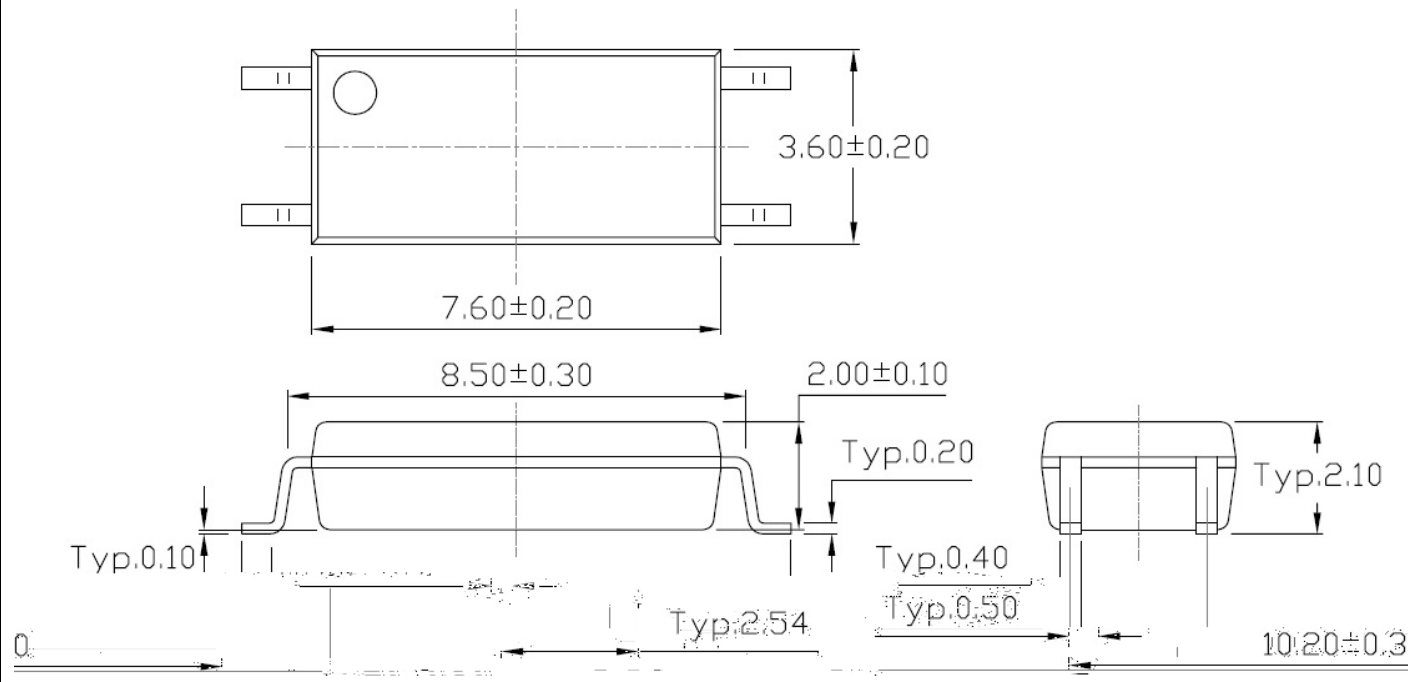


Fig. 14 Test Circuit of Frequency

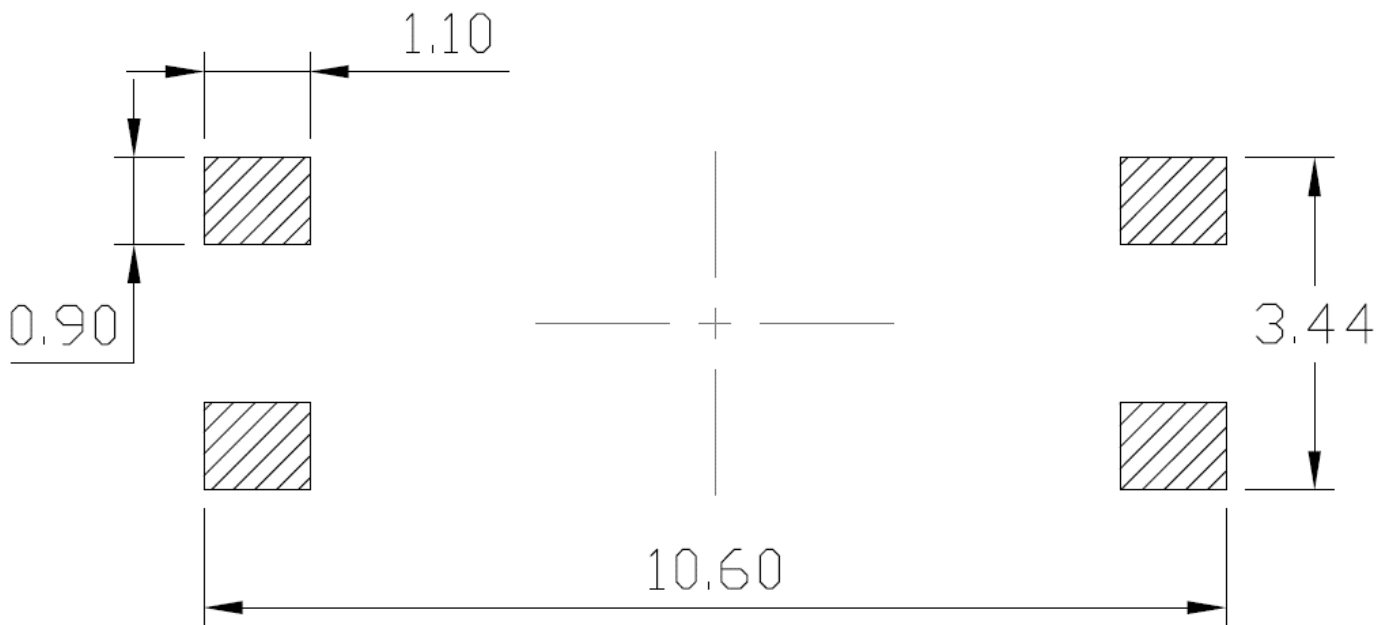


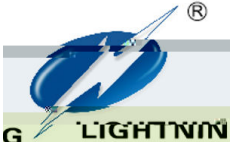


PAC A E DIMENSIONS Dimension in mm &le\$ other / i\$e \$tated=



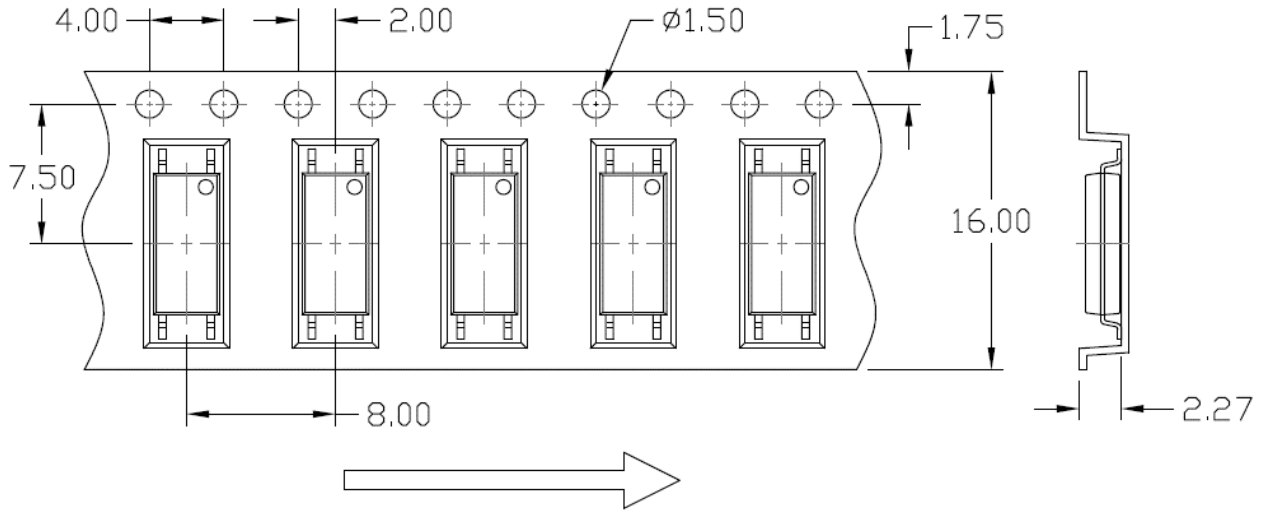
RECOMMENDED SOLDER MASK Dimension in mm &le\$ other / i\$e \$tated=



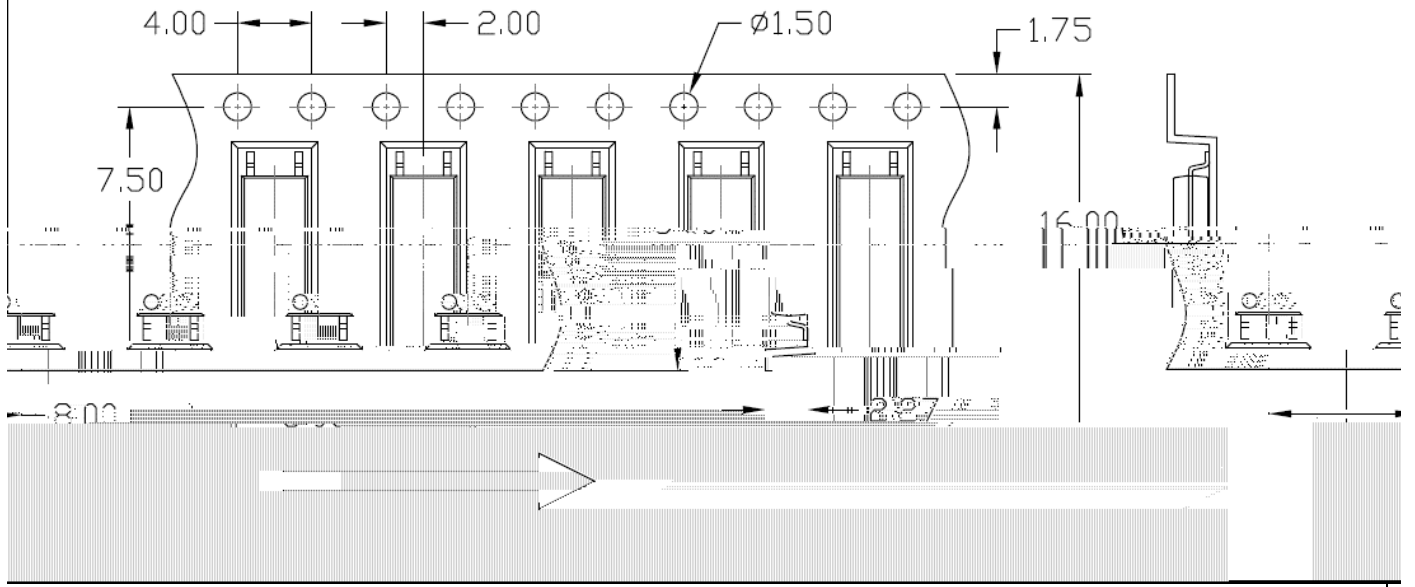


CA)) IE) TAPE SPECIFICATIONS Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1



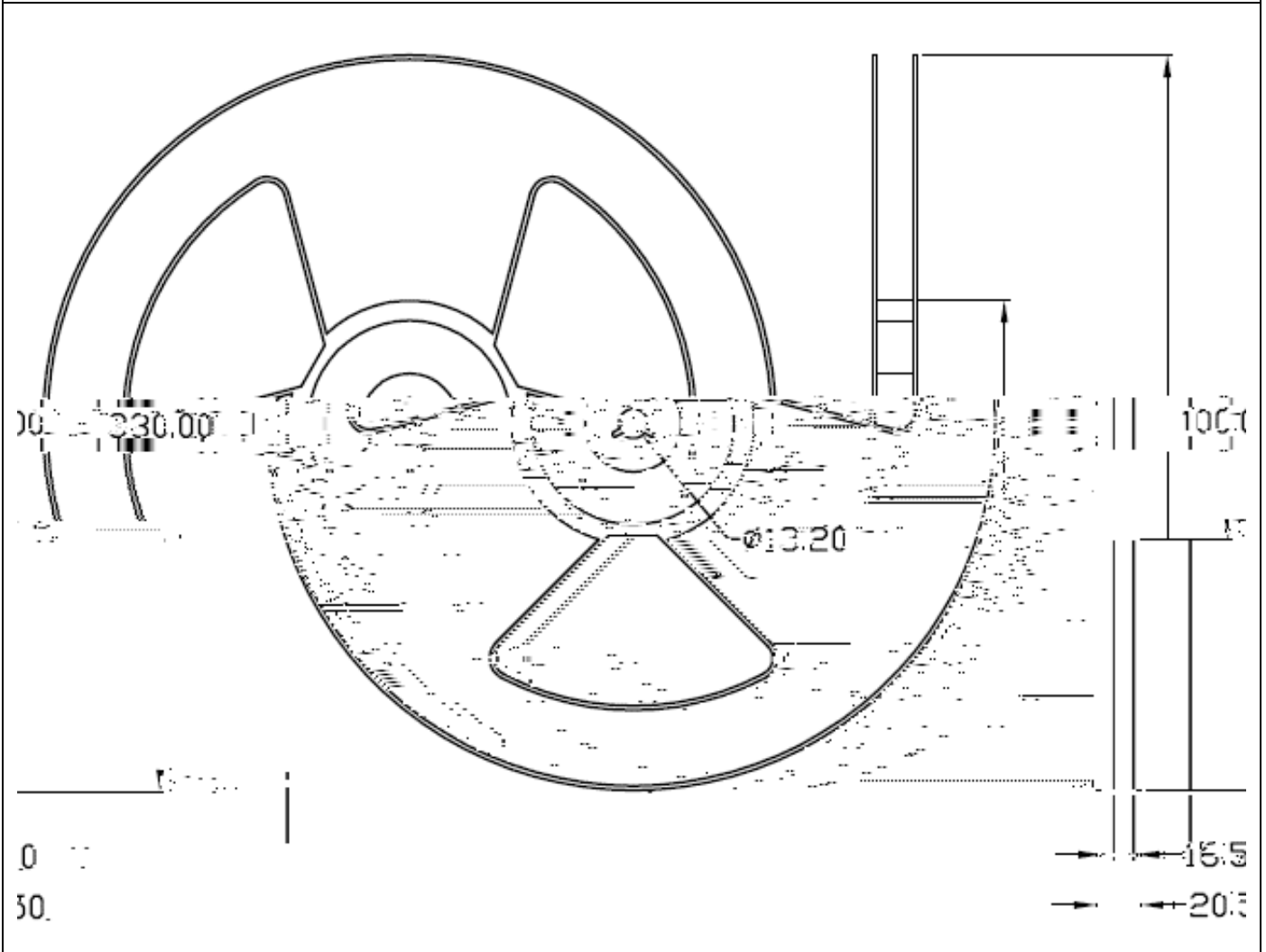
O%tion T2

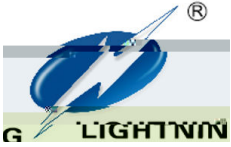




MECHANICAL SPECIFICATIONS Dimensions in mm unless otherwise stated

Option T1 > T2





LSOP4, DC Input, Photo Transistor Coupler

1. ELECTRICAL SPECIFICATIONS

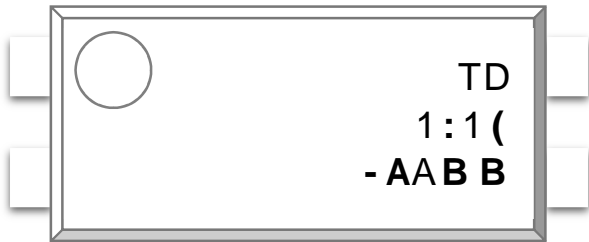
Inner Pin

2.3W ± 3% / -3cm / -3cm ± 0.9cm



OPTIONAL AND MAIN INFORMATION

MAIN INFORMATION



TD @ Company Abbr.
1:1 @ Part Number
- @ -DE Option
A @ Fiscal Year
A @ Manufacturing Code
BB @ B or B2

OPTIONAL INFORMATION

PACKAGE INFORMATION

TD1:1 (CD=3! -

TD : , company Abbr#
101X : *an" 60J1J?J=J!J(J5J3J7J<8
K : Tape and *eel Option 6T1JT?8
G : Green
) :)D1 Option 6) or 4one8

福建天电光电有限公司
FUJIAN LIGHTNING OPTOELECTRONIC CO., LTD.

Part No : XXXXXXXXXXXX Bin Code : X

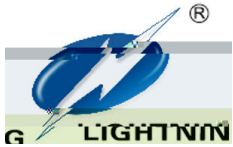
Lot No : XXXXXXXXXXXX

Date Code : XXXX

Q'ty : XXXX pcs

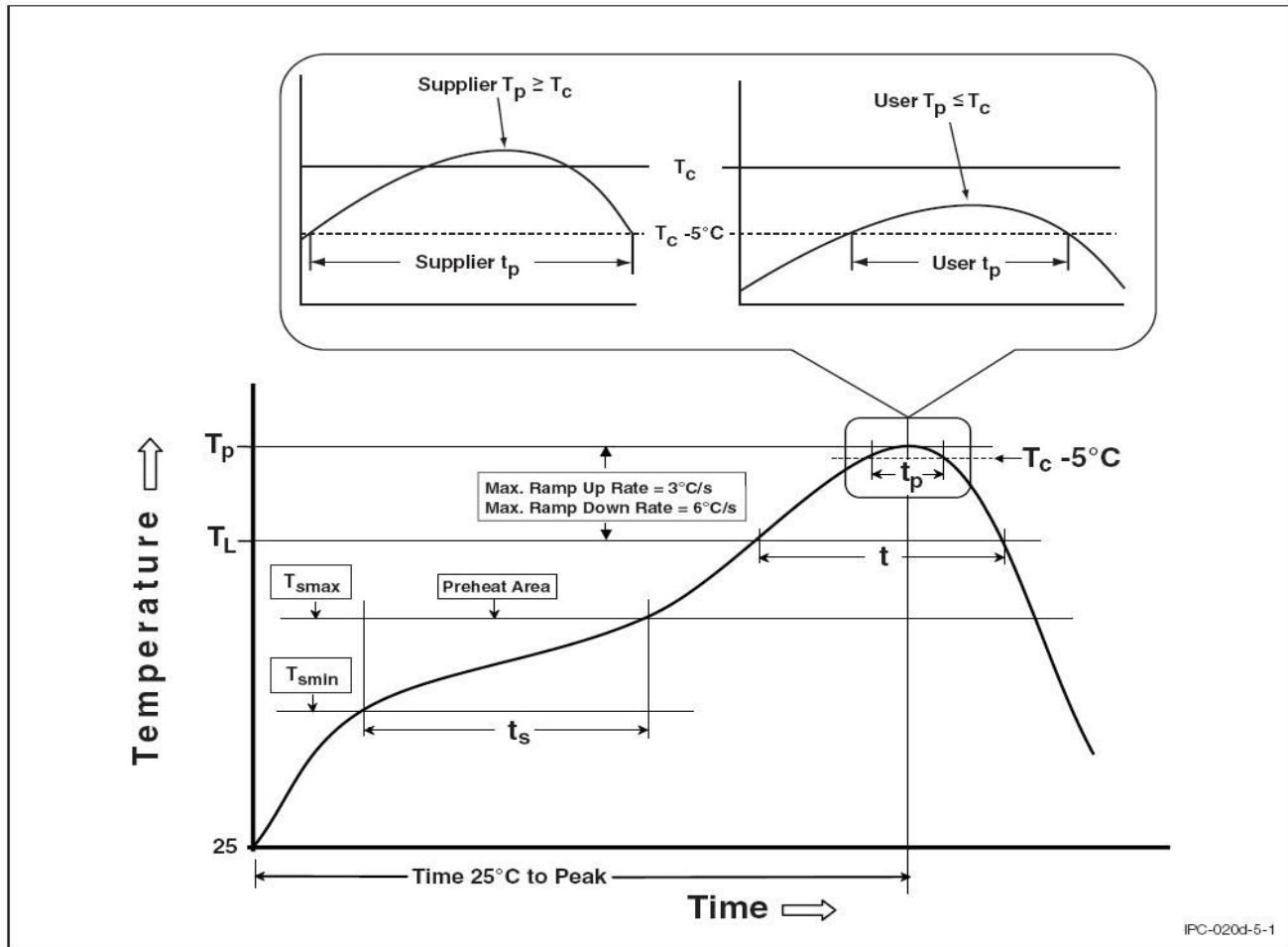
PACKAGE ANTIFLAG

Option	Antiflag	Antiflag Inner 1o?	Antiflag Outer 1o?
T1	=000 2nits! *eel	= *eels!Anner bo-	(Anner bo-JOuter bo- D ! (" 2nits
T?	=000 2nits! *eel	= *eels!Anner bo-	(Anner bo-JOuter bo- D ! (" 2nits



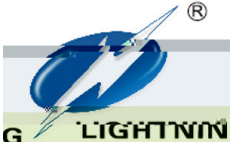
OPERATIONAL INFORMATION

OPERATIONAL INFORMATION



IPC-020d-5-1

Profile Feature	Sn3P1 Assembly Profile	P13Free Assembly Profile
Temperature +in# 6T _{min}	100	1 (0/ ,
Temperature +a-# 6T _{max}	1 (0	?00/ ,
Time 6ts from 6T _{min} to T _{max}	50.1?0 seconds	50.1?0 seconds
* amp.up * ate 6t _L to t 8	=/ , Jsecond ma-#	=/ , Jsecond ma-#
Liquidous Temperature 6TL	17=/ ,	?13/ ,
Time 6t _L + aintained Abo&e 6TL	50 : 1 (0 seconds	50 : 1 (0 seconds
ea" ;ody ac"age Temperature	?=(/ , L0/ , J.(/ ,	?50/ , L0/ , J.(/ ,
Time 6t 8 within (/ , of ?50/ ,	?0 seconds	=0 seconds
* amp.down * ate 6T to TL	5/ , Jsecond ma-	5/ , Jsecond ma-
Time ?(/ , to ea" Temperature	5 minutes ma-#	7 minutes ma-#



LSOP4, DC Input, Photo Transistor Coupler

DISC#AIME)

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The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.

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This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.

Please contact LAG ' T4A4G sales agent for special application request.

Immersion unit's body in solder paste is not recommended.

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Discoloration might be occurred on the package surface after soldering, reflow or long time use. It neither impacts the performance nor reliability.